74HC4094-Q100; 74HCT4094-Q100

8-stage shift-and-store bus register

Rev. 2 — 14 November 2018

Product data sheet

1. General description

The 74HC4094-Q100; 74HCT4094-Q100 is an 8-bit serial-in/serial or parallel-out shift register with a storage register and 3-state outputs. Both the shift and storage register have separate clocks. The device features a serial input (D) and two serial outputs (QS1 and QS2) to enable cascading. Data is shifted on the LOW-to-HIGH transitions of the CP input. Data is available at QS1 on the LOW-to-HIGH transitions of the CP input to allow cascading when clock edges are fast. The same data is available at QS2 on the next HIGH-to-LOW transition of the CP input to allow cascading when clock edges are slow. The data in the shift register is transferred to the storage register when the STR input is HIGH. Data in the storage register appears at the outputs whenever the output enable input (OE) is HIGH. A LOW on OE causes the outputs to assume a high-impedance OFF-state. Operation of the OE input does not affect the state of the registers. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of $V_{\rm CC}$.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- · Complies with JEDEC standard JESD7A
- · Input levels:
 - For 74HC4094-Q100: CMOS level
 - For 74HCT4094-Q100: TTL level
- Low-power dissipation
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF; R = 0 Ω)

3. Applications

- Serial-to-parallel data conversion
- Remote control holding register

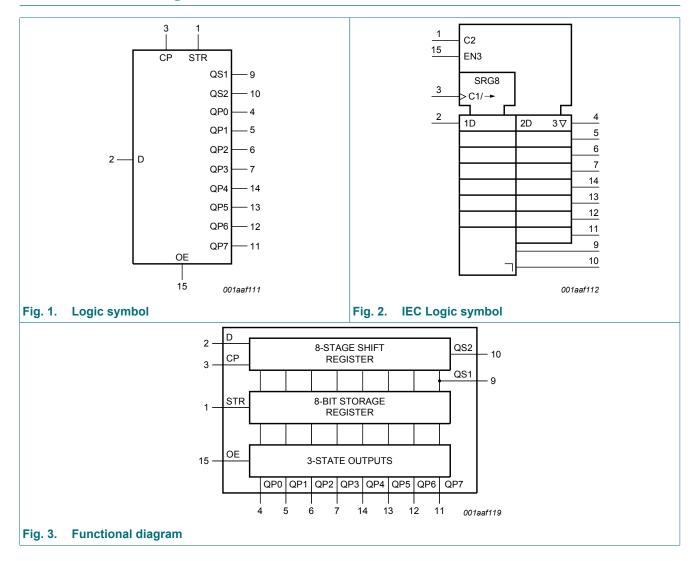


4. Ordering information

Table 1. Ordering information

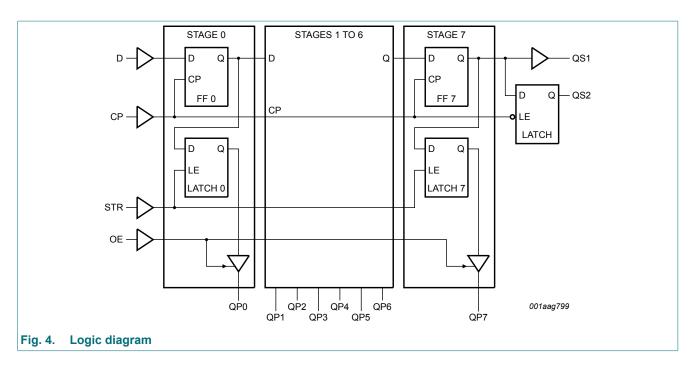
Type number	Package			
	Temperature range	Name	Description	Version
74HC4094D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1
74HCT4094D-Q100			body width 3.9 mm	
74HC4094DB-Q100	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1
74HCT4094DB-Q100			body width 5.3 mm	
74HC4094PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

5. Functional diagram



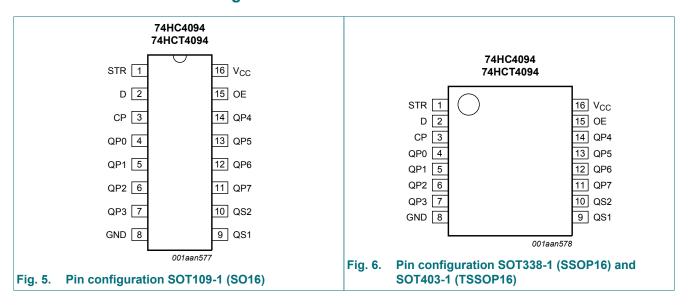
Product data sheet

2/19



6. Pinning information

6.1. Pinning



Product data sheet

3 / 19

6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
STR	1	strobe input
D	2	data input
СР	3	clock input
QP0 to QP7	4, 5, 6, 7, 14, 13, 12, 11	parallel output
GND	8	ground supply voltage
QS1, QS2	9, 10	serial output
OE	15	output enable input
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table

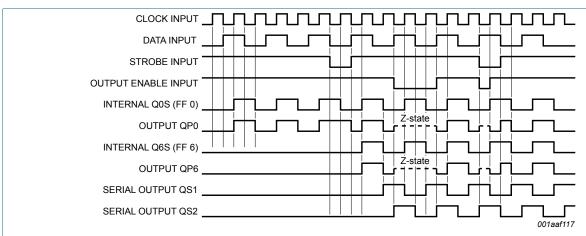
 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ Z = HIGH-impedance \ OFF-state; \ NC = no \ change;$

 \uparrow = positive-going transition; \downarrow = negative-going transition;

Q6S = the data in register stage 6 before the LOW to HIGH clock transition;

Q7S = the data in register stage 7 before the HIGH to LOW clock transition.

Inputs				Parallel o	outputs	Serial out	Serial outputs		
СР	OE	STR D		QP0	QPn	QS1	QS2		
↑	L	X	Х	Z	Z	Q6S	NC		
\downarrow	L	X	Х	Z	Z	NC	Q7S		
↑	Н	L	X	NC	NC	Q6S	NC		
↑	Н	Н	L	L	QPn -1	Q6S	NC		
1	Н	Н	Н	Н	QPn -1	Q6S	NC		
\downarrow	Н	Н	Н	NC	NC	NC	Q7S		



At the positive clock edge, the information in the 7th register stage is transferred to the 8th register stage and the QSn outputs.

Fig. 7. Timing diagram

Product data sheet

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-	±25	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-	-50	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	SO16, SSOP16 and TSSOP16 packages	[1]	-	500	mW

^[1] For SO16: P_{tot} derates linearly with 8 mW/K above 70 °C. For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74H	C4094-C	Q100	74H	Unit		
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC40	94-Q100									•
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND};$ $V_{CC} = 6.0 \text{ V}$	-	-	±0.5	-	±5.0	-	±10.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	1
74HCT4	094-Q100									
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	8.0	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND};$ $V_{CC} = 5.5 \text{ V}$	-	-	±0.5	-	±5.0	-	±10	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; I_O = 0 A								
		per input pin; STR input	-	100	360	-	450	-	490	μΑ
		per input pin; OE input	-	150	540	-	675	-	735	μΑ
		per input pin; CP input	-	150	540	-	675	-	735	μΑ
		per input pin; D input	-	40	144	-	180	-	196	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit see Fig. 12.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC40	94-Q100			1	1					
t _{pd}	propagation	CP to QS1; see Fig. 8 [1]								
	delay	V _{CC} = 2.0 V	-	50	150	-	190	-	225	ns
		V _{CC} = 4.5 V	-	18	30	-	38	-	45	ns
		V _{CC} = 5 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	33	-	38	ns
		CP to QS2; see Fig. 8 [1]								
		V _{CC} = 2.0 V	-	44	135	-	170	-	205	ns
		V _{CC} = 4.5 V	-	16	27	-	34	-	41	ns
		V _{CC} = 5 V; C _L = 15 pF	-	13	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	13	23	-	29	-	35	ns
		CP to QPn; see Fig. 8 [1]								
		V _{CC} = 2.0 V	-	63	195	-	245	-	295	ns
		V _{CC} = 4.5 V	-	23	39	-	49	-	59	ns
		V _{CC} = 5 V; C _L = 15 pF	-	20	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	18	33	-	42	-	50	ns
		STR to QPn; see Fig. 9 [1]								
		V _{CC} = 2.0 V	-	58	180	-	225	-	270	ns
		V _{CC} = 4.5 V	-	21	36	-	45	-	54	ns
		V _{CC} = 5 V; C _L = 15 pF	-	18	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	17	31	-	38	-	46	ns
t _{en}	enable time	OE to QPn; see Fig. 10 [1]								
		V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
t _{dis}	disable time	OE to QPn; see Fig. 10 [1]								
		V _{CC} = 2.0 V	-	41	125	-	155	-	190	ns
		V _{CC} = 4.5 V	-	15	25	-	31	-	38	ns
		V _{CC} = 6.0 V	-	12	21	-	26	-	32	ns
t _t	transition	QPn and QSn; see Fig. 8 [1]								
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	1
t _W	pulse width	CP HIGH or LOW; see Fig. 8								
		V _{CC} = 2.0 V	80	14	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	4	-	17	-	20	-	ns
		STR HIGH; see Fig. 9								
		V _{CC} = 2.0 V	80	14	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	4	-	17	-	20	-	ns
t _{su}	set-up time	D to CP; see Fig. 11								
		V _{CC} = 2.0 V	50	14	-	65	-	75	-	ns
		V _{CC} = 4.5 V	10	5	-	13	-	15	-	ns
		V _{CC} = 6.0 V	9	4	-	11	-	13	-	ns
		CP to STR; see Fig. 9								
		V _{CC} = 2.0 V	100	28	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	10	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	8	-	21	-	26	-	ns
t _h	hold time	D to CP; see Fig. 11								
		V _{CC} = 2.0 V	3	-6	-	3	-	3	-	ns
		V _{CC} = 4.5 V	3	-2	-	3	-	3	-	ns
		V _{CC} = 6.0 V	3	-2	-	3	-	3	-	ns
		CP to STR; see Fig. 9								
		V _{CC} = 2.0 V	0	-14	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-5	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-4	-	0	-	0	-	ns
f _{max}	maximum	CP; see Fig. 8								
	frequency	V _{CC} = 2.0 V	6.0	28	-	4.8	-	4.0	-	MHz
		V _{CC} = 4.5 V	30	87	-	24	-	20	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	95	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	103	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF; } f = 1 \text{ MHz;}$ [2] $V_I = \text{GND to } V_{CC}$	-	83	-	-	-	-	-	pF

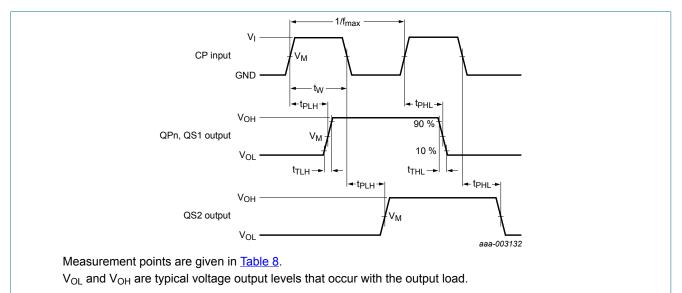
Symbol Parameter		Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HCT4	094-Q100					<u>'</u>					•
t _{pd}	propagation	CP to QS1; see Fig. 8	[1]								
	delay	V _{CC} = 4.5 V		-	23	39	-	49	-	59	ns
		V _{CC} = 5 V; C _L = 15 pF		-	19	-	-	-	-	-	ns
		CP to QS2; see Fig. 8	[1]								
		V _{CC} = 4.5 V		-	21	36	-	45	-	54	ns
		V _{CC} = 5 V; C _L = 15 pF		-	18	-	-	-	-	-	ns
		CP to QPn; see Fig. 8	[1]								
		V _{CC} = 4.5 V		-	25	43	-	54	-	65	ns
		V _{CC} = 5 V; C _L = 15 pF		-	21	-	-	-	-	-	ns
		STR to QPn; see Fig. 9	[1]								
		V _{CC} = 4.5 V		-	22	39	-	49	-	59	ns
		V _{CC} = 5 V; C _L = 15 pF		-	19	-	-	-	-	-	ns
t _{en}	enable time	OE to QPn; see Fig. 10	[1]								
		V _{CC} = 4.5 V		-	20	35	-	44	-	53	ns
t _{dis}	disable time	OE to QPn; see Fig. 10	[1]								
		V _{CC} = 4.5 V		-	21	35	-	44	-	53	ns
t _t	transition	QPn and QSn; see Fig. 8	[1]								
	time	V _{CC} = 4.5 V		-	7	15	-	19	-	22	ns
t _W	pulse width	CP HIGH or LOW; see Fig. 8									
		V _{CC} = 4.5 V		16	7	-	20	-	24	-	ns
		STR HIGH; see Fig. 9									
		V _{CC} = 4.5 V		16	5	-	20	-	24	-	ns
t _{su}	set-up time	Dn to CP; see Fig. 11									
		V _{CC} = 4.5 V		10	4	-	13	-	15	-	ns
		CP to STR; see Fig. 9									
		V _{CC} = 4.5 V		20	9	-	25	-	30	-	ns
t _h	hold time	Dn to CP; see Fig. 11									
		V _{CC} = 4.5 V		4	0	-	4	-	4	-	ns
		CP to STR; see Fig. 9									
		V _{CC} = 4.5 V		0	-4	-	0	-	0	-	ns
f _{max}	maximum	CP; see Fig. 8									
	frequency	V _{CC} = 4.5 V		30	80	-	24	-	20	-	MHz
		V _{CC} = 5 V; C _L = 15 pF		-	86	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF; } f = 1 \text{ MHz;}$ $V_I = \text{GND to } V_{CC} - 1.5 \text{ V}$	[2]	-	92	-	-	-	-	-	pF

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{en} is the same as t_{PZH} and t_{PZL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{t} is the same as t_{THL} and t_{TLH} .

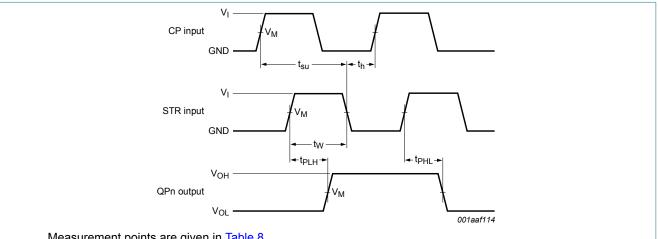
[2] C_{PD} is used to determine the dynamic power dissipation (P_{D} in μ W). $P_{D} = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; V_{CC} = supply voltage in V; N = number of inputs switching; $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

11.1. Waveforms and test circuits



Propagation delay input (CP) to output (QPn, QS1, QS2), output transition time, clock input (CP) pulse Fig. 8. width and the maximum frequency (CP)



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Propagation delay strobe input (STR) to output (QPn), strobe input (STR) pulse width and the clock set-up Fig. 9. and hold times for strobe input

Product data sheet

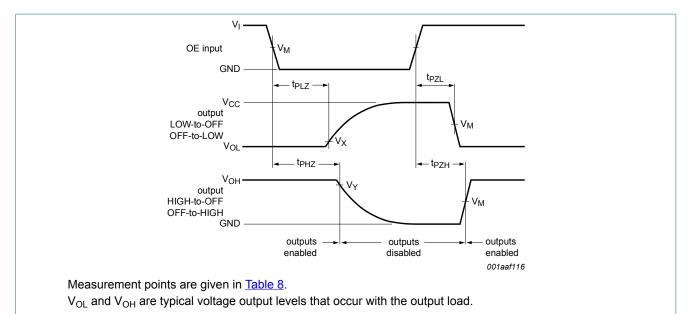


Fig. 10. Enable and disable times

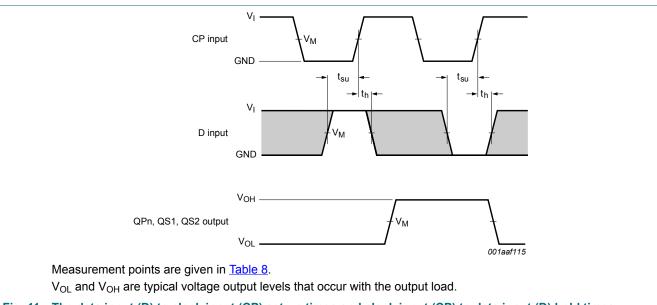
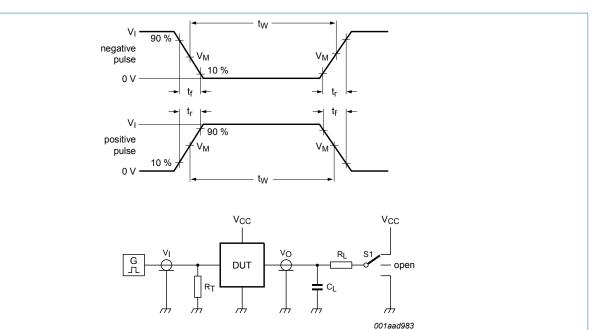


Fig. 11. The data input (D) to clock input (CP) set-up times and clock input (CP) to data input (D) hold times

Table 8. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC4094-Q100	0.5V _{CC}	0.5V _{CC}	0.1V _{OH}	0.9V _{OH}
74HCT4094-Q100	1.3 V	1.3 V	0.1V _{OH}	0.9V _{OH}



Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig. 12. Test circuit for measuring switching times

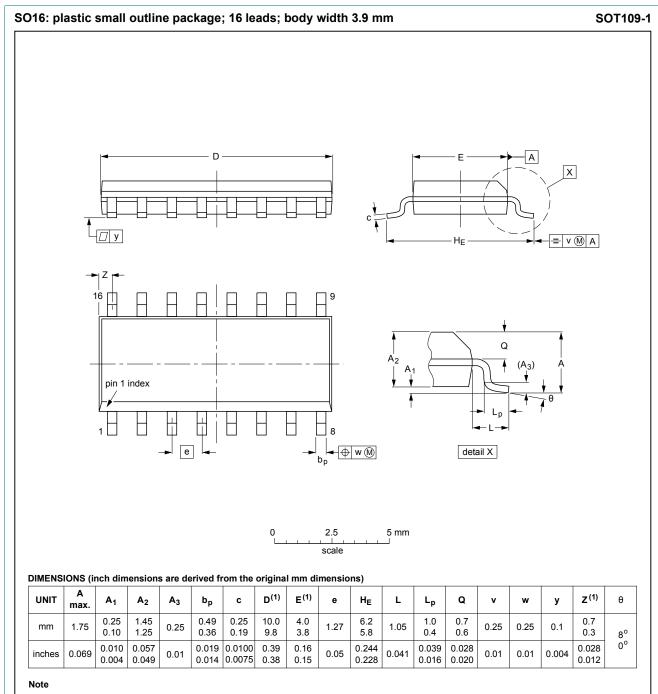
Table 9. Test data

Туре	Input		Load		S1 position			
	V _I	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74HC4094-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74HCT4094-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

Product data sheet

13 / 19

12. Package outline



1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig. 13. Package outline SOT109-1 (SO16)

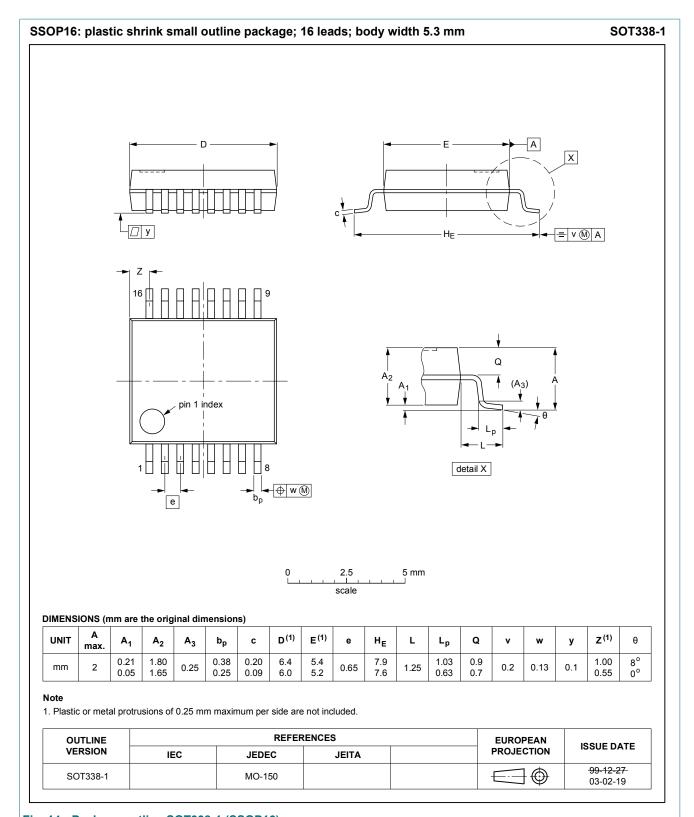


Fig. 14. Package outline SOT338-1 (SSOP16)

Product data sheet

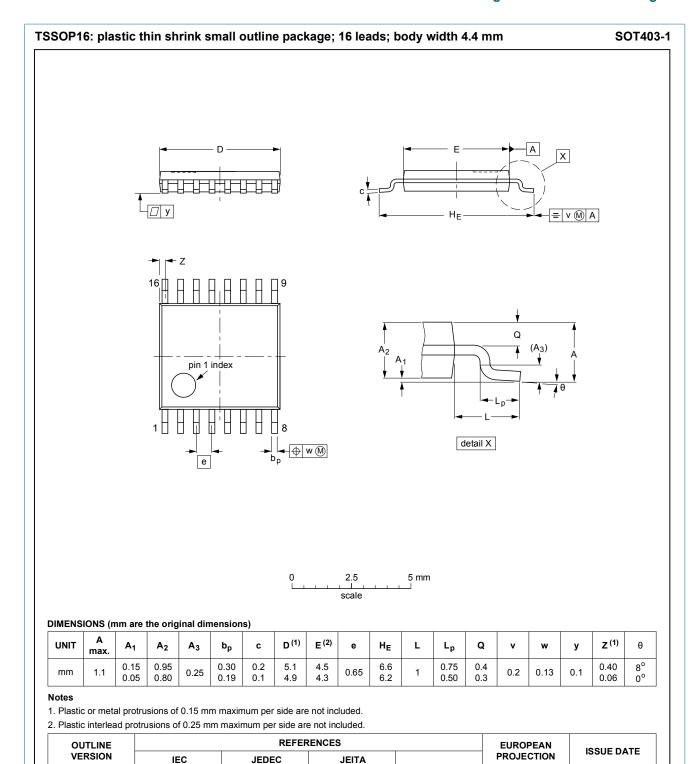


Fig. 15. Package outline SOT403-1 (TSSOP16)

MO-153

Product data sheet

SOT403-1

99-12-27

03-02-18

 $\bigoplus \bigoplus$

13. Abbreviations

Table 10. Abbreviations

Acronym	Description	
CMOS	Complementary Metal Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
НВМ	Human Body Model	
MM	Machine Model	
TTL	Transistor-Transistor Logic	

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4094_Q100 v.2	20181114	Product data sheet	-	74HC_HCT4094_Q100 v.1
Modifications:	The format of this data sheet has been redesigned to comply with the identity guidelines Nexperia. Legal texts have been adapted to the new company name where appropriate. Fig. 4 and Fig. 7 corrected.			
74HC_HCT4094_Q100 v.1	20130130	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or

equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own triple.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

For more information, please visit: http://www.nexperia.com
For sales office addresses, please send an email to: salesaddresses@nexperia.com
Date of release: 14 November 2018

[©] Nexperia B.V. 2018. All rights reserved